

Transmission Electron Microscopy of Polymer Materials

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The lecture was created for courses on Polymer Morphology. Great majority of information in this lecture holds for non-polymeric materials as well.

Focus of the lecture:

(1) the basic methods of TEM, important for polymers (BF, DF, SAED, EDX)

(2) how to interpret/get information from the micrographs of polymer systems

* other methods of TEM not so important for polymer systems just briefly listed

* basic theory of electron microscopy has been explained in the 1st lecture of the course

Background of the slides:

blue = theory; **green** = examples; **yellow** = calculations; **grey** = supplements

Micrographs in this lecture:

(Almost) all micrographs in this lecture come from our laboratory + majority of samples from IMC \Rightarrow we can discuss/collaborate on whatever will be shown in the presentation.

Part 1

Brief Introduction to TEM

Contents

Four basic modes of TEM

Signal in TEM from in macro-, microscopic and atomistic view

Notes:

- Supplement #1 gives overview of other TEM methods and possibilities
- Supplement #2 gives basic information about SEM hardware components

TEM microscopy :: four main modes



TEM/BF Au standard dark Au particles on light C film



TEM/ED Au standard electron diffraction of Au on C



TEM/DF Au standard white Au particles on dark C film



TEM/EDS Au_standard elemental analysis of Au on C

TEM/BF

- transmitted electrons, direct image (bright field)
- >90% of applications in polymer science

TEM/DF

- diffracted electrons, direct image (dark field)
- special applications connected with crystal structure

TEM/ED

- electron diffraction
 - = diffracted electrons
- nanocrystals (inorganics, metals, polymer fillers...)

TEM/EDX

- characteristic X-rays
- microanalysis (like in SEM, but in nanometer scale)

TEM :: macroscopic view :: scheme of the microscope



Note2: TEM is more similar to LM than to SEM. The image is formed in one step like in LM, not point-by-point like in SEM.

TEM :: microscopic view :: beam-specimen interactions



TEM detector (fluorescent screen, film, or camera) \Rightarrow used as a detector for **TEM/BF, TEM/DF, TEM/ED**

TEM :: atomistic view :: electron-atom interactions



Comparison of signals in TEM (upper row) and SEM (lower row).

Supplement #1 :: TEM :: summary of methods

1) Conventional TEM (CTEM; covered in this lecture): standard methods : BF, DF, ED ~ SAED useful supplement: EDX ~ EDS ~ microanalysis These are the main methods used for polymer systems \Rightarrow main part of this lecture

- 2) Analytical TEM (ATEM; mostly for inorganics, but also organics/polymers): ATEM = CTEM + STEM mode + analytical methods such as EDX, EELS => ATEM = maps of elemental composition in nanometer scale
- 3) High-resolution TEM (HRTEM; almost exclusively for inorganic materials): HRTEM = atomic resolution due to combination of direct + diffraction imaging => HRTEM = micrographs showing individual atoms (mostly in stable crystals)
- 4) Cryogenic-TEM (Cryo-TEM, mostly in biology, also polymer solutions): Cryo-TEM = TEM + device for freezing/imaging samples at LN2 temperature => Cryo-TEM = imaging of bio-objects or polymer nanoparticles in solution
- 5) 3D-TEM (mostly in biology, also other fields): 3D-TEM = [CTEM or ATEM] + [stage for high tilts] + [SW for 3D-reconstruction] => 3D-TEM = 3D-models of microscopic objects such as viruses, organelles...
- * TEM sample holders: single/double-tilt, low-background, cryo-holder...
- * TEM other methods: E-TEM (environmental TEM: sample in 'natural' conditions), EFTEM (better contrast + analysis), HVTEM (high voltage & resolution, obsolete), Cs/Cc-aberration corrected TEM (corrections => even higher atomic resolution)
- * TEM combinations: e.g. HRTEM + EFTEM + aberration corrections
- * TEM other methods: (HAADF, EELS, CBED, PED, SE...) => see Wikipedia, textbooks

Supplement #2a :: TEM components

Electromagnetic lenses (analogous to SEM)



A magnetic lens consists of a coil of copper wires inside the iron pole pieces. A current through the coils creates a magnetic field (symbolized by red lines) in the bore of the pole pieces. The rotationally symmetric magnetic field is inhomogeneous in such a way that it is weak in the center of the gap and becomes stronger close to the bore. Electrons close to the center are less strongly deflected than those passing the lens far from the axis. The overall effect is that a beam of parallel electrons is focused into a spot (so-called cross-over).

In a magnetic field, an electron experiences the Lorentz force $\mathsf{F}\colon$

$$F = -e (E + \mathbf{v} \times B)$$

$$|F| = evBsin(\mathbf{v}, B) -eE$$

E: strength of electric field B: strength of magnetic field e/v: charge/velocity of electrons

The focusing effect of a magnetic lens therefore increases with the magnetic field B, which can be controlled via the current flowing through the coils. As it is described by the vector product, the resulting force F is perpendicular \mathbf{v} and \mathbf{B} . This leads to a helical trajectory of the electrons and to the magnetic rotation (image is rotated in respect of the object). Particle with charge Q is moving with velocity v in the electromagnetic field; electric and magnetic forces are acting on the particle:

$$\mathbf{F} = \mathbf{F}_{\mathrm{E}} + \mathbf{F}_{\mathrm{M}}$$

Electric force **F**_E is given by the intensity of electric field **E**:

 $\mathbf{F}_{E} = \mathbf{Q} \cdot \mathbf{E}$

Magnetic force F_M is given by magnetic induction **B**:

 $\mathbf{F}_{M} = \mathbf{Q} \cdot (\mathbf{v} \times \mathbf{B})$

Force acting on electron:

 \rightarrow F = -e·(E + v×B)

Connection with real life: electromagnetic lens deflects electrons due to inhomogeneous magnetic field; strength of the lens can be adjusted by changing current (logically: $B \propto N \times I$). * *Moreover, electron trajectories can be calculated – this is employed in construction of microscopes.*

Supplement #2b :: TEM components

Electron guns, Apertures and Detectors



- common TEM has just one detector for BF/DF/ED camera at the bottom (+ possibly EDX)
- analytical TEM (ATEM) usually has additional detectors (EDX obligatory) + EELS, HAADF...

Part 2

More theory and resolution of TEM

Contents

- Basic calculations (analogous to SEM):
 (Velocities, wavelengths and penetration depths of electrons)
- TEM specific: electron diffraction (Why it cannot be observed in SEM?
- Contrast, magnification and resolution in TEM (Finishing of the story from the introductory lecture...

TEM :: Velocity, wavelength and penetration of electrons Calculations like in SEM – just the relativistic corrections are more important.

Why are the relativistic corrections more important in TEM?

typical SEM: accelerating voltage up to 30 kV – velocity ~ 0.3c – corrections not critical typical TEM: accelerating voltage 200–300 kV – velocity close to c – corrections needed

***** Velocity of electrons:

(2nd equation with rel. corrections

$$v(U) = \sqrt{\frac{2eU}{m_{\rm e}}}$$
$$v(U) = c \cdot \sqrt{1 - \frac{1}{\left(1 + \frac{eU}{m_{\rm e}c^2}\right)^2}}$$

Wavelength of electrons:

(2nd equation with rel. corrections

$$\lambda(U) = \frac{h}{\sqrt{2m_{\rm e}eU}}$$
$$\lambda(U) = \frac{h}{\sqrt{2m_{\rm e}eU}} \cdot \frac{1}{\sqrt{1 + \frac{eU}{2m_{e}c^{2}}}}$$

Penetration depth of electrons:

- no corrections needed in this case
- ultrathin sections for TEM ~50nm
 ⇒ less than R (almost) all cases

$$R(M,\rho,Z,U)=27.6\frac{MU^{5/3}}{\rho Z^{8/9}}$$

Technical notes:

- For sample calculations and justifications of the non-relativistic formulas see the previous lecture on SEM.
- Relativistic formulas taken from: [Reimer, Kohl: Transmission electron microscopy, 2008].

TEM :: magnification

Why does a TEM microscope contain so many lenses?



Why is there so many lenses in TEM?

Magnification modes of TEM:

- LM = Low Magnification
- MM = Medium...

• HM = High...

What is the difference? ...in modern TEM there is no difference from the point of view of user; the switching among the modes is automatic. ...but alignments for are usually separated.

...among other things because of the magnification modes (and also because of ED...).

Is it possible to add one more lens and get higher magnification?...Yes, of course.Therefore, can we increase the resolution to infinity?...No, of course not.

Why not? ...after exceeding the resolution limit, we get no further details in the image.

TEM :: contrast

Resolution in TEM is usually sufficient for polymer materials \rightarrow contrast is the key.

Contrast × **sample preparation**:

Sample preparation is the key factor.

In biology and **polymer science** (where the contrast is usually weak)

we use **staining** (treating of specimen with staining agents = substances with high Z)

- OsO₄ specific staining of polymers with C=C bonds
- RuO₄ not-so-specific, less predictable, less reproducible, but (almost) universal method
- numerous other stains with heavy elements (uranyl acetate, phosphotungstic acids)...

Contrast × **objective** aperture:

Discussed in detail in previous slides.

The smaller the aperture, the higher the contrast.

BUT too small aperture \rightarrow low signal + low resolution \rightarrow see next.

Contrast × accelerating voltage:

In general: lower U \Rightarrow higher contrast. BUT: too low U \Rightarrow low resolution & high sample damage. Note: in SEM the lower U usually means lower sample damage.

Contrast × **other factors**:

1) You can buy a TEM objective lens optimized for higher contrast at the cost of resolution .

2) You can switch from TEM/BF to TEM/DF: higher contrast at the cost of signal – see next.



TEM :: resolution Summary: resolution in various modes and types of TEM.

★ Theoretical TEM resolution = diffraction condition: d = $\lambda/2 \approx 0.003$ nm (C-C bond ~ 0.15nm). BUT this resolution cannot be achieved due to lens aberrations (more details = next slides). If your own eye lens was as good as our best electromagnetic lens, then you'd be legally blind!

The best electromagnetic lens is equivalent to the bottom of a Coke bottle if used as a magnifying glass.

- ***** CTEM microscopes = modern TEM's in TEM/BF \rightarrow d \approx 0.3 nm @ 100kV.
 - Moreover, approximate rule says that the best resolution $\approx 1/10$ of sample thickness.
 - Typical thickness of polymer samples (UMT \approx 50nm) \Rightarrow resolution \approx 1/10*50nm = 5nm.
 - Conclusion: CTEM resolution is Ok for micro/nanostructures but not for individual atoms.
- HRTEM microscopes = High-Resolution TEM microscopes:
 - HRTEM's use higher accelerating voltages (d = λ/2; λ=h/√2meU), some imaging tricks and/or (expansive) correctors of lens aberrations (Cs, Cc) ⇒ d ≈ 0.1 nm @ 200-300kV.
 - Conclusion: in HRTEM, you can see individual atoms (in thin, beam-resistant samples).
- ***** ATEM microscopes = Analytical TEM microscopes:
 - Modern ATEMs (= microscopes with STEM + EDX...) are usually also HRTEM microscopes.
 - Conclusion: in top ATEMs, you can achieve atomic resolution also in STEM, EDX, EELS...
 - This is always connected with STEM mode in TEM: scanning of very thin specimen (note that max.resolution ≈ 1/10 of specimen thickness) in a top TEM microscope (you need all possible corrections and optimizations) and you get the images of atoms (but your material must withstand this!)

Suppl. #3 :: Why TEM resolution is worse than $\lambda/2$?

Part 1: Numerical aperture & marginal rays.

Numerical aperture (NA)

is a dimensionless number that characterizes the range of angles over which the system can accept or emit light (the exact definition of NA may vary for different fields of optics).

Numerical aperture in microscopy

LM: NA = $n * \sin\theta$ = refractive index of the medium * sin(semi-angle of the objective lens) TEM: NA = $\sin\alpha \rightarrow n$ for vacuum is 1; aperture angle θ is frequently denoted as α in TEM



- * NA in microscopy is always defined with respect to given point, typically to the center of the focused sample = to the central point at working distance.
- * Refractive index is a part of the definition, as denser medium with higher n refracts light and effectively increases the acceptance angle (Snell's law).
- ★ Higher NA ~ θ ~ α ⇒ less paraxial rays = more marginal rays = more lens aberrations.
 (lens aberrations = non-ideal imaging → see next slide)

Suppl. #3 :: Why TEM resolution is worse than $\lambda/2$?

Part 2: Marginal rays and lens aberrations.

Glass lenses for LM are almost perfect.

Moreover, they can be combined together to compensate for the aberrations. Result: aplanatic/achromatic objective \rightarrow LM resolution is limited by d $\approx \lambda/2 \approx 200$ nm.

Electromagnetic lenses for TEM are very poor.

Moreover, their improvement is complicated (in the past: impossible, now: very costly). Result: the resolution in TEM is much worse than $d \approx \lambda/2 \approx 0.03/2 \approx 0.015$ Å



Spherical aberration is the more critical in TEM (logical: colors ≈ energies of electrons are more-or-less similar)

Suppl. #3 :: Why TEM resolution is worse than $\lambda/2$?

Part 3: End of the story from the introductory lecture.

Diffraction-limited resolution in TEM (Rayleigh): $\delta_d = \lambda/2\sin(\alpha) = 0.50\lambda/\sin(\alpha) \approx 0.61\lambda/\alpha$ \diamond derivation of the basic formula for δ_d = diffraction limit $d=\lambda/2 \rightarrow$ introductory lecture \diamond plus: finite aperture: $\sin(\alpha)$; Abbe(0.50) \rightarrow Rayleigh(0.61); small angles: $\sin(\alpha) \approx \alpha$



* Theory: Brandon & Kaplan: Microstructural Characterization of Materials (2008), pp. 188-189.

Part 3

TEM/BF – interpretation of micrographs

Contents

✤ Theory:

Explanation of contrast in TEM/BF using ray optics

 \rightarrow nice application of theory from the introductory lecture!

Examples:

Application of TEM/BF for polymer systems Visualization of nanoparticles/nanofillers and ultrathin sections

TEM/BF :: typical applications (for polymer systems)

Two main types of contrast in TEM/BF:

(1) mass-thickness contrast = thicker/higher-Z areas appear darker

(2) diffraction contrast = diffracting/scattering areas appear darker

Important advantage of TEM/BF in comparison with STEM/BF: higher resolution



TEM/BF micrographs of various polymer systems:

(a) morphology nanoparticles – polyurethane nanofibers decorated with Ag nanoparticles preparation: 2uL of the nanofiber suspension onto Cu-grid with C-film, left to evaporate
 (b) subsurface morphology of bulk polymers – PET surface implanted with Ni ions

preparation: cut small piece of sample, embed in epoxy resin, cut cross-section of the surface with UMT (c) internal morphology of bulk polymers – dispersion of TiNT in e-beam modified PP:

preparation: cut square pyramid with upper surface 0.1x0.1mm, cut with Cryo-UMT, observe in TEM 19

TEM/BF :: two main types of contrast (for polymer systems)

Two main types of contrast in TEM/BF:

(1) mass-thickness contrast: higher mass (= higher Z) or thicker areas \Rightarrow darker (2) diffraction contrast: areas that diffract (or scatter) more electrons \Rightarrow darker



TEM/BF :: Theory :: Lenses, images, and diffraction



TEM/BF :: Ray optics :: Imaging and diffraction mode



A two-lens microscope (from previous slide) in imaging mode. The 2nd lens (L₂) is focused on (real) image.

* lens L₂ is stronger than in diffraction mode (Power = 1/f₂)

A two-lens microscope (the same as above) in diffraction mode. The 2nd lens (L_2) is focused on diffraction pattern.

* lens L₂ is weaker than in imaging mode (Power = 1/f₂)

sample and its imagesdiffraction pattern

Note: power of the lens ~ 1/[focal length] in EM can be altered by changing the strength of the current.

TEM/BF :: Theory :: Mass-thickness and diffraction contrast

TEM without objective aperture – just mass-thickness contrast.



Object that neither transmits nor diffracts electrons \Rightarrow black.



Object that transmits but does not diffract electrons \Rightarrow white.



Object that both transmits and diffracts electrons \Rightarrow white.



Object that does not transmit but diffracts electrons \Rightarrow white.

TEM/BF :: Theory :: Mass-thickness and diffraction contrast

TEM with the objective aperture in the center – bright field imaging.



Object that transmits but does not diffract electrons \Rightarrow white. \rightarrow contrast in TEM/BF

Object that does not transmit but diffracts electrons \Rightarrow black. \rightarrow contrast in TEM/BF

TEM/BF :: Theory :: Mass-thickness and diffraction contrast

TEM with the objective aperture outside center – dark field imaging.



Object that neither transmits nor diffracts electrons \Rightarrow black.



Object that transmits but does not diffract electrons \Rightarrow black. \rightarrow contrast in TEM/DF



Object that both transmits and diffracts electrons \Rightarrow gray. \rightarrow contrast in TEM/DF



Object that does not transmit but diffracts electrons \Rightarrow white. \rightarrow contrast in TEM/DF

TEM/BF :: Examples

Visualization of nanoparticles: mass-thickness contrast (+ diffraction contrast).



TEM/BF micrographs: Au-NP with tunable size on C-film. Mass-thickness contrast dominates (proof: OBJ aperture).



TEM/BF, higher magnification.

Sample preparation:

- Preparation of Au-NC. (controlled reduction of Au³⁺
- 2) Preparation of C-films. (vacuum evaporation device
- Transfer of C-films on Cu grids.
 (alternative: buy the grids
- 4) Drop 2µl of Au colloid onto carbon-coated Cu-grid suck off the excess of solution.
- 5) Insert the grid into TEM and observe in BF 😳

TEM/BF :: Examples

Microscopy of ultrathin sections: diffraction contrast (+ mass-thickness contrast).



TEM/BF of several PS-based block copolymers stained with RuO₄, showing microphase-separated blocks.

Sample preparation:

- Preparation of ultrathin sections and their capture onto microscopic Cu-grids (ultramicrotome @ RT)
- 2) Staining of samples on the grids by RuO₄ vapors.
 (as usual, one phase is stained (faster than the other by RuO₄
- 3) Insertion of the grid into TEM and observation in BF.

How can we verify if our sample exhibits also absorption contrast?

- remove OBJ aperture
- look if you can still differentiate the structure:
 - \rightarrow yes \Rightarrow mass-thickness contrast
 - \rightarrow no \Rightarrow only diffraction contrast
- this case:

after removing OBJ aperture the structure still partially visible

Part 4 TEM/DF – interpretation of micrographs

Contents

Theory:

explanation of contrast in TEM/DF using ray optics

 \rightarrow simple ray-tracing diagrams of TEM/BF vs. TEM/DF another instructive application of ray optics in TEM

Examples:

1) application of TEM/DF in order to increase contrast

2) application of TEM/DF in order to real structure of crystals

TEM/DF :: Theory :: Ray-tracing diagram of the microscope

Principle of DF. types of DF. Jak získat TEM/DF mikrofotografii?

Physical principle of DF: We detect real image formed only by diffracted beams.

Types of DF:

We need to transmit just diffracted beams. This can be achieved in two main ways: dirty-DF (is easier to achieve and understand) and axial-DF (yields better micrographs). The modes of DF are best shown in ray-tracing diagrams.



How to get TEM/DF micrograph: 1) get TEM/BF, 2) for axial-DF, incline the PE beam, 3) switch to ED, 4) select a diffracted beam by OBJ-aperture, 5) switch back to BF \Rightarrow because we have selected diffracted beams (instead of transmitted beams), we get TEM/DF (instead of BF). 29

TEM/DF :: Examples

Example 1. Application of TEM/DF in order to increase contrast.

Practical example \downarrow taken from [Transmission Electron Microscopy and Diffractometry, str.76].



Fig. 2.14. Spherical δ' precipitates in an Al-Li alloy at 80,000 X magnification. Left: BF image. Right: DF image from (100) diffraction spot, unique to δ' precipitates.

Theoretical explanation \downarrow taken from [TEM Tecnai manual, Chapter: Modes, page: 21].



The origin of the high contrast is shown schematically in the figure to the left. Bright-field as well as dark-field images display changes in intensity across the image. In both cases the total range of intensities is roughly similar. In brightfield images, however, the changes in intensity come on top of a high and unvarying signal – the undiffracted electrons. If one attempts to expose for a longer time to improve the signal, the negative becomes overexposed. In the case of the dark-field the background signal is much lower, leading to a much higher contrast in the image.

Note: With negatives the inherent lower contrast of the bright-field image is inescapable. With slow-scan CCD images it is however possible to subtract the uniform background from the image and stretch the contrast.

TEM/DF :: Examples

Example 2: Application of TEM/DF for visualization of real structure of crystals.

TEM/DF is frequently used for study of specific structures/dislocations of real crystals.



Fig. 7.59. Illustration of an APB with $\delta r = a/2 \langle 111 \rangle$ in the B2 structure.

- The basic principle is not difficult:
- specific dislocations give specific diffractions
- if we select a specific diffraction and visualize only the beams from this diffraction, we see the dislocation

Typical procedure: we visualize the dislocation in TEM/BF, switch to TEM/SAED in order to get the diffractogram from selected area, localize the specific diffraction(s),



Fig. 7.60. (a) Bright-field and (b) axial dark-field images of APBs in ordered Fe₃Al using a (100) superlattice diffraction. After [7.2].

select them by means of OBJ aperture and switch to TEM/DF mode. By comparing TEM/BF and TEM/DF we can determine the dislocation type. In this slide, we show APB disclocation (upper image), which is manifested on TEM/BF and TEM/DF micrographs (lower image) with inverted contrast (the inverted contrast is typical of APB).

Part 5

TEM/SAED – interpretation of diffractograms

Diffraction :: Level 1 = distances

- 1) crystals and crystallographic planes
- 2) crystallographic planes and Bragg's Law
- 3) Bragg's Law and diffraction experiments
- 4) Bragg's Law and TEM/SAED => camera equation
- 5) TEM/SAED in the microscope => ray-tracing
- Types of diffractograms, examples
 - * types: monocrystal, polycrystalline, and oriented samples
 - * examples: identification of structures, limitations...

Diffraction :: Level 2 = distances + positions

- (optional just in Appendix better understanding of TEM/SAED (examples: calibration and indexing of diffraction patterns
- Diffraction :: Level 3 = distances + positions + intensities
- (optional just in Appendix brief intro to diffraction theory
 (example: ab initio calculation of powder diffraction with Jupyter
 Diffraction :: Level 4...

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(just mentioned here for the sake of completeness (structure analysis, dynamic theory, magnetic structures...
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Note: distances, positions and intensities = distances, positions and intensities of the diffractions spots/rings on the diffraction pattern with respect to the origin = to the position of primary beam.

Crystals and crystallographic planes (revision of general chemistry).



Materials can crystallize in one of **seven crystal systems**: cubic, hexagonal, trigonal, tetragonal, orthorhombic, monoclinic, and triclinic.

In crystal lattices we define lattice planes, defined by Miller and/or diffraction indexes (hkl).

Interplanar spacing d_{hkl} (i.e. the distance between [hkl] planes)
can be calculated
d_{hkl} = function(a,b,c,
$$\alpha$$
, β , γ ,h,k,l)
(justification \rightarrow consult XRD textbooks
(calculation in Jupyter: \rightarrow Ex.1
$$\frac{1}{d_{hkl}^2} = \left[\frac{h^2 \sin^2 \alpha}{a^2} + \frac{k^2 \sin^2 \beta}{b^2} + \frac{l^2 \sin^2 \gamma}{c^2} + \frac{2hk}{ab}(\cos \alpha \cos \beta - \cos \gamma) + \frac{2lk}{ca}(\cos \gamma \cos \alpha - \cos \beta)\right]$$
(1+2 cos α cos β cos γ - cos² α - cos² β - cos² γ)
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Lattice planes and Bragg's Law (revision from the introductory lecture).

Bragg's Law in words:

Maximal interference = diffraction of lattice plane (hkl) is observed just at specific angles (2dsin θ = n λ).

Bragg's Law graphically:



BL and Physics:

- 1) Ray optics
 - (wave reflection
- 2) Wave optics
 - (interference

BL and Mathematics:

 $2d_{hkl}\sin\theta_{hkl} = n \times \lambda$

 $\begin{array}{lll} \mbox{path difference} & \mbox{integer multi-} \\ \mbox{between waves} & \mbox{plication} \\ & \Psi_1 \mbox{ a } \Psi_2 & \mbox{of } \lambda \end{array}$

Bragg's Law and lattice planes:

A crystal contains plains: d_{hkl} = function(a,b,c, α , β , γ ,h,k,l) – see previous page. BL says: diffraction will be observed only for θ_{hkl} such that d_{hkl} will obey $2d_{hkl}sin\theta_{hkl} = n \times \lambda$

Limitations of Bragg's Law:

[1] Distances of diffractions from the center (of diffractogram): direct information $\Rightarrow \theta_{hkl}$. [2] Positions of diffractions: indirect information \Rightarrow just intuitively, based on law of reflection. [3] Intensity: no information \Rightarrow just some sophisticated considerations about atoms in planes..

Bragg's law and diffraction experiments.

General diffraction experiment (with a crystal):



Alternative forms of Bragg's law:

- $2dsin\theta = n\lambda$ \leftarrow basic form, sometimes with diffraction indices : $2d_{hkl}sin\theta_{hkl} = n\lambda$
- $2dsin\theta = \lambda$ \leftarrow without n, because it holds, for example: $2d_{100}sin\theta_{100} = 2\lambda \equiv 2d_{200}sin\theta_{200} = 1\lambda$
- dq = $2\pi n$ \leftarrow with q, because q = $4\pi \sin\theta/\lambda$
- dS = n \leftarrow with S, because S = $2\sin\theta/\lambda$ $\int \rightarrow$ see Ex.2

Bragg's law and diffraction experiments in TEM.



Input data:

- d = interplanar spacing \rightarrow this is what we want
- R = distance of diffraction from the center \rightarrow measure
- θ = diffraction angle \rightarrow to be calculated
- L = this is camera constant \rightarrow has to be calibrated
- λ = wavelength of electrons \rightarrow can be calculated but it is calibrated together with L

Important prerequisites:

Electrons diffract at very low angles and, as a result: $\sin\theta \approx \tan\theta \approx 1/2 * \tan(2\theta)$

 \rightarrow Ex.3

Calculation of d:

- (1) Bragg's law: $2d*\sin\theta = \lambda$
- (2) Geometry of the experiment: $tan(2\theta) = R/L$.
- (3) Prerequisite low angles: $tan(2\theta) = 2sin\theta = R/L$
- (4) Combination of (1+3): Rd = λ L (camera equation)
- (5) The constant λL is determined from calibration, i.e. from the diffraction with a known sample.

Recalculations d \times θ \times **S** \times **q**: Important in practice: see previous page.
TEM/ED :: Theory :: Level 1

Ray-tracing diagram for TEM/SAED experiment.

Physical principle of ED: scattering + interference

- 1) Electrons are elastically scattered on atoms.
- 2) After scattering, the waves interfere and give rise to diffraction patterns.

Types of electron diffraction:

- The basic type of diffraction in TEM is
 SAED = selected-area ED
 - → the area for diffraction is selected by SA aperture
- 2) Modern TEM microscopes have also
 - ED = aperture-less ED
 - → the area for diffraction is selected directly by e-beam
- 3) And many other types...
 - CBED = Convergent Beam ED
 - NBD = NanoBeam ED
 - **PED** = Precession ED ...



How to get TEM/(SA)ED pattern: (1) Get BF image, (2) remove OBJ aperture (3) select area for diffraction (in SAED: using SA-aperture; in ED: using e-beam directly), (4) switch to diffraction and (5) carefully magnify/focus/record the diffraction pattern. 37

TEM/ED :: Types of diffraction patterns

Monocrystal vs. polycrystalline samples.

Simple intuitive model:



Why the monocrystal diffractogram looks like this? \Rightarrow see next.

TEM/ED :: Types of diffraction patterns

Unoriented and oriented polycrystalline samples.

Simple intuitive model:



TEM/ED :: Types of diffraction patterns

Summary: three basic types of diffractograms we can observe in TEM.



Monocrystal.

- = single crystal.
- Diffraction pattern is composed of diffraction spots.
- Each lattice plane gives rise to one spot.
- The distance of the spot from the center is given by Bragg's Law or its TEM equivalent: Camera equation.



Oriented polycrystalline.

- sample consists of manysmall crystals with somepreferred orientation.
- Diffraction pattern is composed of half-moons.
- The position and intensity of half-moons is linked with the orientation.

|--|

Polycrystalline sample.

- sample consists of many small crystals with random orientation.
- Diffraction pattern is composed of rings.
- Each ring is formed by many diffractions from the small crystals.

Precise explanation = Theory/Level 2. In this course, we skip level 2, but see texbooks \rightarrow Laue diffraction condition, Ewald sphere..

[Au standard]

Example 1: Identification of known samples + principle of TEM calibration.

Sample: Au nanoparticles. TEM/SAED diffraction pattern. ED experiment versus XRD calculation. Conclusion: good agreement \Rightarrow it is Au, fcc.



This is also a principle of the TEM/SAED calibration using Camera equation $Rd = \lambda L$: $\Rightarrow R$ is measured (directly on 2D-diffractogram), d is calculated (easy – as already shown). \Rightarrow Then we can determine $\lambda L = CC = camera constant and L = CL = CC/\lambda = camera length.$

We need at least two pieces of software to do such things:

(1) [Red program] converts 2D-diffraction pattern to 1D-diffraction pattern (red curve)

(2) [Blue program] for calculation of theoretical 1D powder diffraction pattern (blue curve) 41

 $[TiO_2 + X]$

Example 2: Identification of unknown/unexpected substances (whose structures are known).



Example 3: Identification of new/unknown compounds (their structures not in databases).



TEM/BF micrograph of TiNT.

⇒ new crystalline modification based on TiO₂ (original synthesis from our laboratory @ IMC).

TEM/ED × PXRD(anatas,rutil).

⇒ we cannot say what it IS,
 but we can claim what it IS NOT,
 i.e. we can claim it is a new structure.

[TiNT]

Example 4: Complete (simple) TEM/BF-EDX-SAED analysis – Fe₃O₄ nanoparticles.



(a) TEM/BF shows the nanoparticle morphology (b) TEM/SAED confirms nanocrystalline character, (c) comparison of calculated PXRD and experimental SAED proves that the nanoparticles are magnetic form of iron oxide, and (d) TEM/EDX verifies the composition.

J Nanopart Res (2016) 18:301. DOI 10.1007/s11051-016-3615-7

Example 5: Complete (more difficult) TEM/BF-EDX-SAED analysis – NaYF₄.



TEM/BF: different for very similar syntheses.

TEM/SAED: different, but TEM/EDX: identical!

Nanoscale 7 (2015) 18096. DOI: 10.1039/c5nr05572e

Detailed explanation \rightarrow

some extra/missing diffractions!?

Supplement :: TEM/SAED :: Homework

HW #1:

Let us have Au crystal, cubic structure, unit cell parameter a = 4,08 Å.

The type of crystalline structure = fcc = face-centered cubic, allowed diffractions have

diffraction indexes (hkl) = (111), (200), (220), (311), (222), (400), (331), (420), (422), ...

Calculate diffraction angles θ and the magnitudes of diffraction vectors S=|S| a q=|q| for:

a) XRD, radiation CuK α (λ = 1.54 Å)

b) TEM/ED, electrons @ accelerating voltage 120 kV

Motivation:

1) Write a small, but real program in Python (the result should be a table like this).

2) Verify, if diffraction angles and vectors depend on wavelength.

Hint for HW:

All formulas (calculation of d(hkl), λ ...) have been given in previous slides/lectures. Table in Python can be made using print+formatting, NumPy or Pandas \rightarrow check www.

HW #2:

- In [Ex.3] we have a "Graphical proof" that for small angles: $2\sin(\theta) = \tan(2\theta) = 2\theta$.
- Make an analogous "Symbolic proof" using Taylor series (the result should look like <u>this</u>).

Motivation:

- 1) Using Taylor series to prove approximate relations is quite common trick in Physics.
- 2) Make sure that you understand the Taylor series trick (you may add a graphical proof).
- 3) Practice Python/SymPy using SymPy, you can solve similar problems in the future...

Part 7 TEM/EDX – interpretation of spectra

Contents

- Theory: just brief overview
 (because the principle of TEM/EDX ~ SEM/EDX
- Examples: just one case study (illustrating improved resolution in TEM/EDX (even in a TEM microscope without STEM mode)

TEM/EDX :: Theory

Principle of TEM/EDX, types of EDX, and higher resolution in comparison with SEM.

Principle of TEM/EDX: \rightarrow exactly the same as in SEM/EDX.

Types of TEM/EDX: \rightarrow two basic types of TEM/EDX, like in SEM







TEM/BF: Au on C



How to get the spectrum and the map?

- Spectrum: (1) BF, (2) select area with beam (3) remove OBJ, (4) insert EDX det. (5) measure
- EDX-map: collect in STEM mode, like in the case of SEM/EDX mapping \Rightarrow you need ATEM

Higher resolution of TEM/EDX in comparison with SEM/EDX.

ATEM/EDX map of SrTiO₃. with atomic resolution. Result from EMC2012. Microscope: FEI Titan G2.





Example 1: Revision of EDX and illustration that the spectra look like from SEM.



TEM/EDX of CeO₂ nanocubes for immunolabeling.
 Inset = final table from standardless ZAF analysis
 Quantitative analysis – limited precision!



Qualitative evaluation of EDX:

- Ce,O CeO₂ nanocrystals
- C,Cu supporting C-film on Cu-grid
- Si,O silicon oil, dust

Example 2: High resolution of TEM/EDX even without STEM – HAP nanocomposite.



TEM/BF micrograph showing siloxane filled with nanocrystals of hydroxyapatite (HAP). [job ID 876-4]

Problem: the black spots are agglomerates of HAP, or some impurities from the sample preparation?



Answer - TEM/EDX: black spots are HAP. Matrix (light gray) contains just C, Si, O. Particles (black spots) contain also Ca, P. (chemical formula of hydroxyapatite: Ca₁₀(PO₄)₆(OH)₂ (H has no EDX signal, Cu is the grid, Mg is an admixture.

Example 3: Complete TEM/BF-EDX-SAED analysis – Fe₃O₄ nanoparticles.



(a) TEM/BF shows the nanoparticle morphology (b) TEM/SAED confirms nanocrystalline character, (c) comparison of calculated PXRD and experimental SAED proves that the nanoparticles are magnetic form of iron oxide, and (d) TEM/EDX verifies the composition.

J Nanopart Res (2016) 18:301 DOI 10.1007/s11051-016-3615-7

Supplement :: TEM/EDX :: Homework

HW #3:

Download the spectrum below from www-pages of the course and index = mark all peaks.



Preliminary information is a key for interpretation of EDX spectra, in our case we knew the following:

- The analyzed nanoparticles should be: NaYF₄:Yb³⁺/Er³⁺@NaYF₄:Nd³⁺
- The nanoparticles were deposited on a C-coated Cu-grid for TEM.
- The concentration of Er³⁺ is very low, maybe below detection limit, but Yb³⁺ and Nd³⁺ should be visible.
- The nanoparticles are enveloped by biopolymers and used for lightupconverting applications (biolabeling).

Motivation: (1) Practice EDX analysis and (2) working with a Jupyter templates. Hints: Employ the EDX-table from EM1:SEM + Jupyter template from www of the course. Note: The rules explained in the previous lecture EM1:SEM hold for TEM/EDX as well.

Part 8 TEM - supplements

Contents

- Special sample holders
- Analytical TEM microscopes

Sample preparation for TEM (in Polymer science)

Supplement :: Special sample holders

Single-tilt holder = standard holder, position for one sample, tilt only along one axis It is used for BF and DF; possible for ED of micro/nanopowders and basic EDX analyses.

Multiple holder = the same as above, but positions for more samples (usually 2-5).

Double-tilt holder = tilt along two axes \Rightarrow primarily for ED of monocrystals.

Low-background holder = holder made of Be – no background in EDX \Rightarrow for microanalysis.

Note: there are various combinations, frequent is low-background double-tilt holder.

Cryo-holders.

Cryo-holder + other HW and SW in TEM + equipment for flash-freezing \Rightarrow CryoTEM. Cryo-TEM is used for sensitive biological specimen to minimize sample damage (especially in combination with 3D-microscopy, which requires many tilts = high exposure of the sample) or for studies of nanoparticles in (flash-frozen) solutions.

Straining/deformation holders.

Straining/deformation holders are used to elongate/deform electron transparent specimens in order to study deformation mechanisms *in situ*. This is used mostly for metals (other specimens are difficult or even impossible to fix reasonably if they are ultrathin).

Supplement :: Scheme of analytical TEM = ATEM

What are the advantages of STEM in TEM microscopes?



ATEM microscope can control the scanning of the beam on the sample, which adds new possibilities: a) STEM itself (useful in DF b) EDX mapping (high resolution c) detection of other signals that does not make much sense in standard TEM: EELS, SE, BSE...

Supplement :: Sample preparation for TEM.

Key problem: how to make samples transparent for electrons.

See also sample preparation in SEM lecture!

(1) Nanopowders: transparent "by themselves" – deposit on Cu-grid with C-film and observe.

(2) Micropowders: a) if possible, pulverize into nanopowder and proceed like in item (1).b) if not, embed in an epoxy resin and proceed like in items (3,4) below.

(3) 3D-samples, soft: (almost all biology and polymer science) \Rightarrow ultramicrotomy



(4) 3D-samples, hard: (chemistry, physics, geology...) \Rightarrow cutting, thinning, etching.



(5) Old, interesting, but rarely used technique: replication (see older textbooks).(6) New, recent, modern technique: FIB microscopy (see newer textbooks and www).

Supplement :: Cryo-TEM :: Chitosan-g-ssDNA in water

TEM of (nano)particles in solution is more-and-more requested – so at least one example.



Cryo-TEM (short exposure, good results):

- clear background = thin amorphous ice
- particles visible (no core-shell structure)
- size of particles agrees with prev. results

Cryo-TEM (longer exposure \Rightarrow artifacts!):

- gray striped zones/areas crystalline ice
- core-shell structure of particles artifact
- both artifacts observed at longer exposure

Supplement :: **3D-TEM** :: principle

3D-TEM is more-and-more popular, namely in biology – so at least the principle.

The 1st way how to get 3D-information about an object: series of tilts.

five tilts of a sphere





The 2nd way how to get 3D-information about an object: series of sections.

five sections of a sphere





five sections of a disk









Note #1: SW for 3D-reconstructions – complex!

Note #2: Many tilts \rightarrow e-beam damage \rightarrow CryoTEM.

Example illustrating that 3D-TEM works.

↓ http://www.embl.de/research/units/scb/briggs/



3D reconstruction of HIV-1 virions using cryo-electron microscopy.

Conclusions & summary

- ***** We have explained the four basic methods of TEM microscopy:
 - TEM/BF = mass-thickness & diffraction contrast
 - TEM/DF = image formed by diffracted electrons
 - TEM/ED = diffraction pattern (formed by diffracted electrons)
 - TEM/EDX = microanalysis, analogy to SEM/EDX, but higher resolution
- The lecture was focused on understanding and interpretation of TEM micrographs and diffraction patterns.

Other pieces of information:

- We have learnt more about magnification, contrast and resolution of TEM
- We have also shown some calculations connected with TEM/SAED
 - → basic calculations: d(hkl), Bragg's Law & camera equation
 - \rightarrow advanced calculations: KDT, calculation of diffraction pattern of Au nanocrystals
- We have discussed some other aspects of TEM, such as: key importance of sample preparation for TEM studies and briefly also advanced TEM microscopes such as ATEM, HRTEM...

[Example 1] Calculation of d(hkl) in Jupyter

Note: illustration that complex formulas are easier/more readable in Jupyter than in Excel...



Out[6]: 6.296242378027061

[Example 2] Diffraction experiments vs. $\theta \times S \times q$.





 $2d*\sin\theta = \lambda$...BL with omitted n

...this is quite common, as it holds (for example): $d_{200} = d_{100}/2$

...therefore : $2d_{200} * \sin\theta_{200} = \lambda \Leftrightarrow d_{100} * \sin\theta_{100} = 2 * \lambda$



 $d*q = 2\pi$...BL: we exchanged diffraction angle θ with (magnitude of) diffraction vector q d*S = 1 ...BL: we exchanged diffraction angle θ with (magnitude of) diffraction vector S

Diffraction angle θ may be at most 90° (2 θ = 180°) – logical: see the image above. In range 0-90° it holds: increase in $\theta \Rightarrow$ increase in sin $\theta \Rightarrow$ increase in S \Rightarrow increase in q. \Rightarrow i.e. there is a proportionality among diffraction angle and diffraction vectors.

[Example 3] Graphical proof that for small angles: $2sin(\theta) = tan(2\theta)$

def f1(x): return(tan(2*x))
def f2(x): return(2*sin(x))
def f3(x): return(2*x)

Trick: standard plotting of tangent would join points at -oo and +oo
def f1_modif(x): return(np.where(np.abs(f1(x)>10),np.nan,f1(x)))

```
plt.plot(X,f1_modif(X), label='tan(2*x)')
plt.plot(X,f2(X), label='2*sin(x)')
plt.plot(X,f3(X), label='2*x')
plt.xlim(-4,4)
plt.ylim(-3,3)
plt.legend()
plt.grid()
plt.show()
```



← Part of the script in Jupyter/Python: graphs of functions $f(\theta) = 2\sin(\theta)$, $\tan(2\theta) = 2\theta$ showing that it holds $2\sin(\theta) \approx \tan(2\theta) \approx 2\theta$ for small θ

Link to a several scripts, which show:

- 0) Calculation of d(hkl).
- 1) Fact that diffraction angles in ED are low.
- 2) Fact that for low diffraction angles the camera equation holds, using... ...numerical verification of the relation $2\sin(\theta) \approx \tan(2\theta) \approx 2\theta$
 - ...symbolic verification of the relation using Taylor expansions
 - ...graphical verification of the relation which is illustrated in this slide

Appendix Complete TEM-BF-EDX-SAED analysis

Illustration of a more complex problem This is extended example from the first part of the presentation

Case study :: Light upconverting NaYF₄ nanoparticles

Introduction & description of the problem from the point of view of microscopy.



Colloidal solutions of light upconverting nanocrystals: NIR light excites their luminescence. J Am Chem Soc **128** (2006) 7444-7445.



- Luminescence: emission of light by a substance.
- Luminescent nanoparticles: nanoparticles that luminise.
- Usage of common luminescent nanoparticles (such as QD): solar cells, data storage, photocatalysis, bioimaging...
- Disadvantage of common nanoparticles in bioimaging: luminescence induced by UV light, which...
 - ...damages biological tissues + has low penetration depth ...causes high background autofluorescence
- Advantage of light upconverting nanoparticles in bioimaging: luminescence induced by NIR light, which...
 - ...produces visible light by energy transfer upconversion (ETU) ...easily penetrates and does not damage biological tissues

NaYF₄:Yb³⁺/Er³⁺ nanocrystals, prepared at our Institute. Purpose: cover with a polymer, fill into microspheres... (origin of samples: Dept. of polymer particles, IMC, Czech Rep.)

Tasks for the microscopic part of the work:

- (1) Visualize the nanoparticles.
- (2) Visualize the polymer shell around the nanoparticles.
- (3) Are the nanoparticles hexagonal or cubic form of $NaYF_4$?

Problem #1: Simultaneous visualization of the nanoparticles and their shell. Solution: TEM/BF at **multiple** magnifications \rightarrow example of microscopic scaling problem.



Prepared nanoparticles (summary):

- Inorganic matrix (IUPAC name) sodium yttrium fluoride (1:1:4)
 NaYF₄
- Doping with Yb³⁺ and Eu³⁺ in order to get upconversion: NaYF₄:Yb³⁺/Er³⁺ (Y:Yb:Eu=57:39:4)
- Covering with silica and its amino derivative in order to improve biocompatibility: NaYF₄:Yb³⁺/Er³⁺&SiO₂ NaYF₄:Yb³⁺/Er³⁺&SiO₂-NH₂

Visualization of nanoparticles:

- ✤ easy: 2µL on C-coated Cu-grid
- ✤ TEM/BF @ 120 kV
- BUT: difficult to see nanoparticles + shell simultaneously
- \Rightarrow here: multiple magnifications
- \Rightarrow general solution: see next

Problem #2: Verification, if the nanoparticles exhibit the expected NaYF₄ structure. Note: Similar syntheses of NaYF₄ give quite different results, situation gets complicated...



TEM/BF: different for very similar syntheses.

TEM/SAED: different, but TEM/EDX: identical! Comparison SAED(exp) x PXRD(calc): some extra/missing diffractions!?

Problem #2: Verification, if the nanoparticles exhibit the expected NaYF₄ structure. Explanation – important additional information: there are two crystal structures of NaYF₄...



 α -NaYF₄ - unexpected cubic, space group $Fm\overline{3}m$ unit cell parameters: a = 5.47 Å less efficient in light upconverting β-NaYF₄ – expected acc.to synthesis conditions hexagonal, space group $P\overline{6}$ ($P\overline{6}2m$, $P6_3/m$) unit cell parameters: a = 5.96 Å, c = 3.51 Å more efficient in light upconverting

* Outputs from **PowderCell** – a freeware program, used here for PXRD calculations.

Problem #2: Verification, if the nanoparticles exhibit the expected NaYF₄ structure. Explanation for TEM/SAED of synthesis A \Rightarrow mixture of cubic and hexagonal phase.



Problem #2: Verification, if the nanoparticles exhibit the expected NaYF₄ structure. Explanation for TEM/SAED of Synthesis B \Rightarrow pure hexagonal phase + preferred orientation.



Conclusion: the missing diffractions are due to extremely strong preferred orientation. 69



Problem #2: Verification, if the nanoparticles exhibit the expected NaYF₄ structure. Final image from the publication \rightarrow everything is crystal-clear in the end...



Appendix

Diffraction level 1 = distances of diffractions from the center

This is just a summary – levels of diffraction theory:
 Level 1 (main lecture) = distances of diffractions (from the central spot)
 Level 2 (see below) = positions of diffractions (optional, not at exams)
 Level 3 (see below) = intensities of diffractions (optional, not at exams)

\bigstar Example what it all means \rightarrow next slide.

More details about diffraction theory – numerous textbooks and www.

Technical note:

A = common font = scalar (usually real number, but it may be complex as well)

A = bold font = vector (magnitude of the vector is marked with common font)

A = extra bold = complex number \rightarrow emphasizing that the number is complex

Diffraction theory :: Level 1 vs. higher levels

Example: SAED pattern of SnO₂ monocrystal (cassiterite, tetragonal mineral).



Note: We have learnt quite a lot about diffraction, but we still cannot answer the blue questions on the right....

 \rightarrow but see Appendixes.

What can we say about the diffrattogram?

1) Overall appearance:

Diffraction spots \Rightarrow monocrystal. Reminder: each spot = one lattice plane. This is explained by Bragg's Law.

2) Overall symmetry:

The crystal was probably cubic or tetragonal (symmetry of crystal vs. diffractogram?

3) Distances of diffractions: These are explained by Bragg's Law.

(why can we see ALL spots AT ONCE?

- 4) Positions of the diffractions: These are explained by Laue diffraction condition (→ appendix: Diffraction, level 2)
- 5) Intensity of the diffractions:
- These can be calculated (to the 1st approximation) by kinematic diffraction theory (\rightarrow appendix: Diffraction, level 3).
- 6) How to calculate the structure from its diffractogram? (Level 4, beyond our course)
Appendix Diffraction level 2 = positions of diffractions

This part is optional (not at exams)

Introduction/revision for those, who are interested in TEM/SAED.

More details about diffraction theory – numerous textbooks and www.

Technical note:

A = common font = scalar (usually real number, but it may be complex as well)

A = bold font = vector (magnitude of the vector is marked with common font)

A = extra bold = complex number \rightarrow emphasizing that the number is complex

Step 1: Direct lattice and reciprocal lattice (DL and RL); RL vectors **G**^{*}_{hkl}.



Step 2: Direct lattice, reciprocal lattice and Laue diffraction condition (LDC).



Step 3: Laue diffraction condition (LDC) and **Ewald construction (EC)**.

Laue diffraction condition:
$$S = G_{hk}^*$$

What LDC means in real life?

If you want to know more details: wikipedia.org \rightarrow Ewald sphere

⇒ Diffraction occurs ONLY on condition that our diffraction vector **S** is equal to some reciprocal lattice vector \mathbf{G}_{hkl}^* .

Ewald construction is a graphical representation of LDC.

- \Rightarrow EC is just a clever image, which shows when and where the diffraction occurs.
- ⇒ Good message: EC can be used and understood even if you do not know all math behind. BUT you must know how to draw it and remember the key conclusion:



The image shows EC for a crystal, which is just diffracting.

Key conclusion:

Diffraction occurs only if some RL point lies on the Ewald sphere. (i.e. if $S = G^*_{hkl} \Leftrightarrow LDC$)

Step 4: Ewald construction \rightarrow XRD pattern of a monocrystal (= single crystal XRD).

XRD of cubic monocrystal.In orOne axis of the monocrystal parallel with s_0 .In or \Rightarrow no RL point lies on Ewald sphere under this conditionthe or \Rightarrow LDC is not fulfilled – no RL vector is identical to SAt su \Rightarrow no diffraction occurscan be

In order to get diffraction, the crystal must be rotated. At suitable rotation LDC can be fulfilled as shown below:



Conclusions:

1) XRD with single crystal: it is necessary to rotate the crystal ⇒ four-circle diffractometers.
 2) Typical XRD diffractogram = file, which gradually grows and contain lines: h, k, l, l(hkl)...

Step 5: Ewald construction \rightarrow XRD of polycrystalline sample (= powder XRD = PXRD).

PXRD, cubic polycrystalline sample = powder sample.

- (1) Reminder:XRD of a monocrystal (no diffraction; see previous slide)
- (2) Different situation for powder sample: Random orientation of crystallites. Diffraction spots \rightarrow rings. Ewald sphere polycrystalline sample reciprocal lattic

with diffraction rings

Conclusions:

Ewald

sphere

monocrystal

XRD with powder sample: LDC fulfilled automatically ⇒ fixed 2D-detectors are sufficient.
 Typical PXRD diffractogram (with 2D-detector) = rings (intersections of ES and RL spheres).

reciprocal lattice

with diffraction spots

Step 6: Ewald construction \rightarrow **ED** pattern of a monocrystal (= single crystal ED).

ED, cubic monocrystal, oriented with one axis along the incident beam = with vector \mathbf{s}_0 .

(1) Reminder:

XRD of a monocrystal (no diffraction, see previous slides)





Two main differences between XRD and ED:

1) Ewald sphere radius = $1/\lambda$; for X-rays: $\lambda \approx 1$ Å, for elns: $\lambda \approx 0.03$ Å \Rightarrow XRD sphere \rightarrow ED plane.

2) Diffraction spots are elongated for thin crystals $\Rightarrow \epsilon_{hkl} \approx 1/L_{hkl} \Rightarrow XRD$ spots \rightarrow ED ellipsoids.

Conclusions:

1) For ED of a monocrystal, LDC is easily fulfilled due to short λ a elongated diffraction spots. 2) Typical ED diffractogram of a monocrystal = spots = image of one reciprocal lattice plane. 79

Step 7: Ewald construction \rightarrow ED pattern of a polycrystalline sample (= powder ED).

ED, cubic polycrystalline sample = powder sample.





Conclusions:

1) ED of powder/polycrystalline sample is completely analogous to PXRD.

2) Typical ED powder diffractogram: diffraction rings on 2D-camera in the TEM microscope.

Example 1 :: Calibration of TEM/SAED patterns

What do we know from previous slides?

- LDC = Laue Diffraction Condition: Diffraction occurs only if S = G^{*}_{hkl}
- Single crystal electron diffraction patterns show spots at positions = G^{*}_{hkl}
- Powder electron diffraction patterns show rings (~multi-spots) at distances = |G^{*}_{hkl}|
- Magnitude of $|\mathbf{G}_{hkl}^*| = 1/d_{hkl} \Rightarrow$ scalebars in diffractograms are in units [1/nm] or [1/Å].
- Typical calibration procedure:

(1) Find a spot/ring with known *hkl.* (2) Calculate d_{hkl} in [Å]. (3) Measure $|\mathbf{G}_{hkl}^*|$ in [pixels]. (4) Calibrate the image by means of relation: $|\mathbf{G}_{hkl}^*|$ [pixels] = $1/d_{hkl}$ [1/Å] (typically in ImageJ).



Calibration of SAED diffractogram of Au (fcc, a=4.08Å)

- (1) The first diffraction corresponds to plane (111). (this can be found in the literature or calculated
- (2) The corresponding d(hkl) = d(111) = 2.36[Å](literature or calculation \rightarrow calculation in iPython
- (3) The corresponding G*(hkl) = G*(111) = 186/2 = 93[pix] (this we measure directly in ImageJ
- (4) The calibration is then calculated in usual way: G*(111) = 93[pixel] ~ 1/d(111) = 1/2.36 = 0.42[1/Å] 93[pix] = 0.42[1/Å] = 4.2[1/nm] ⇒ 6[1/nm] = 133[pix] and the scalebar is inserted with ImageJ → IJM macro the only not-so-common thing: reciprocal units

! Note: Common units in 2D-diffractograms: [1/nm] (diff.vector S ~ G_{hkl}^*), but in 1D: [1/Å] (q = 2 π S). 81

Example 2 :: Indexing of powder TEM/SAED diffraction patterns

What do we know from previous slides?

- All that was summarized in the previous Example 1 concerning RL vectors.
- Namely: Powder SAED patterns show diffraction rings at distances |G^{*}_{hkl}| = 1/d_{hkl}.
- Moreover: $|\mathbf{G}_{hkl}^*|$ is proportional to S and other diffraction vectors/angles $|\mathbf{G}_{hkl}^*| \propto S \propto q \propto 2\theta$.
- Typical indexing procedure:
 - (1) Just compare experimental 2D-SAED with (2) calculated 1D-PXRD (x-axis in q or S or 2θ).



Example 3 :: Indexing of single-crystal TEM/SAED diffraction patterns

What do we know from previous slides?

- All that was summarized in the previous Example 1 concerning RL vectors.
- Single crystal ED patterns (with defined orientation) show images of defined RL planes.
- Single crystal ED patterns (with random orientation) show random sections through 3D RL.
- Typical indexing procedure (for oriented ED patterns):
 (1) Find two independent RL vectors and (2) Index the spots using vector addition.



Indexing of MXene monocrystal. Plane with zone axis 001.



Final result (without RL vectors and lines). More about MXenes \rightarrow wiki, literature... 83

Appendix Diffraction level 3 = intensities of diffractions

This part is optional (not at exams)

Introduction/revision for those, who are interested in TEM/SAED.

More details about diffraction theory – numerous textbooks and www.

Technical note:

A = common font = scalar (usually real number, but it may be complex as well)

A = bold font = vector (magnitude of the vector is marked with common font)

A = extra bold = complex number \rightarrow emphasizing that the number is complex



Final result = scattering by one volume element dr

$$\begin{split} & |A(\mathbf{q})|^2 \dots \text{intensity of the scattered wave depends on its direction} \approx \theta \approx \mathbf{S} \approx \mathbf{q} \\ & A(\mathbf{q}) = \text{const} * \text{number_of_scatterers_in_unit_volume } * \text{volume_element} \\ & A(\mathbf{q}) = b * n(\mathbf{r}) * d\mathbf{r} \quad \dots b = \text{diffraction length} = \text{different for X-rays, neutrons, electrons...} \\ & A(\mathbf{q}) = \rho(\mathbf{r}) * d\mathbf{r} \quad \dots \rho(\mathbf{r}) = b * n(\mathbf{r}) = \text{electron density in XRD, nuclear density in ND...} \end{split}$$

The above formulas \uparrow are presented here without justification, but they are quite logical. More details are given in good (select carefully!) textbooks about diffraction.

Diffraction :: Level 3 :: Basic formula: $A(q) = \int \rho(r) \exp[iqr] dr$

Step 2: Scattering by two centers - path difference.



2 waves (Ψ_1, Ψ_2), which are scattered by 2 centers (e_1, e_2):

Final result:

Note: The justification holds for any scatterers and/or geometry.

The difference between paths lenghts of 2 waves (Ψ_1, Ψ_2) and **arbitrary** 2 scatterers (e_1, e_2) is $\Delta p = \mathbf{r}(\mathbf{s} - \mathbf{s}_0) =$ the additional distance that Ψ_1 has to travel in comparison with Ψ_2 .

Diffraction :: Level 3 :: Basic formula: $A(q) = \int \rho(r) \exp[iqr] dr$

Step 3: Scattering by two centers - phase difference.

2 waves (Ψ_1, Ψ_2) , which are scattered by 2 centers (e_1, e_2) :



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Diffraction :: Level 3 :: Basic formula: $A(q) = \int \rho(r) \exp[iqr] dr$ Step 4: Generalization for scattering by N scattering centers.

Summation of two exponential waves (the same amplitudes):

 $\Psi_3 = \Psi_1 + \Psi_2 = [A \exp(i\phi_1) + A \exp(i\phi_2)] \times \exp(iX)$

Summation of two exponential waves (different amplitudes):

 $\Psi_3 = \Psi_1 + \Psi_2 = [A_1 \exp(i\phi_1) + A_2 \exp(i\phi_2)] \times \exp(iX)$

Re-writing for two scattered waves $(\Phi_i = \mathbf{qr}_i)$:

 $\Psi_3 = \Psi_1 + \Psi_2 = [A_1 \exp(i\mathbf{qr}_1) + A_2 \exp(i\mathbf{qr}_2)] \times \exp(iX)$

Complex amplitude of two scattered waves:

$$\mathbf{A}_3 = \mathbf{A}_1 + \mathbf{A}_2 = [A_1 \exp(i\mathbf{q}\mathbf{r}_1) + A_2 \exp(i\mathbf{q}\mathbf{r}_2)]$$

Derivation from EMO, Appendix B.

Combine previous eq. and previous slide.

Final formula for amplitude of 2 scattered waves.

Generalization for N waves with different amplitudes:

$$\Psi = \sum_{j=1}^{N} \Psi_j = \left[\sum_{j=1}^{N} A_j \exp(i\mathbf{qr}_j)\right] \times \exp(iX)$$

$$\mathbf{A} = \sum_{j=1}^{N} \mathbf{A}_j = \sum_{j=1}^{N} A_j \exp(i\mathbf{qr}_j) \longrightarrow \begin{array}{l} \text{Generalization:} \\ \text{amplitude of} \\ \text{N scattered waves.} \end{array}$$

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Diffraction :: Level 3 :: Basic formula: $A(q) = \int \rho(r) \exp[iqr] dr$ Step 5: Generalization for scattering by any object (*within RDG approximation*!)

Amplitude of the scatterred wave from a single volume element $d\mathbf{r}$ ($\rho(\mathbf{r}) = density$ of scatterers):

$$A = \rho(\mathbf{r}) \cdot \mathrm{d}\mathbf{r} \tag{1}$$
 Step 1

Amplitude of scattering from two volume elements (A_i are the amplitudes given by Eq. 1, the final amplitude is a complex number because of the phase shifts):

$$\mathbf{A}(\mathbf{q}) = \mathbf{A}_1(\mathbf{q}) + \mathbf{A}_2(\mathbf{q}) = A_1 \exp(i\mathbf{q}\mathbf{r}_1) + A_2 \exp(i\mathbf{q}\mathbf{r}_2)$$
(2) Step 4

Direct generalization of Eq. (2) for the scattering by N volume elements:

Q.E.D.

$$\mathbf{A}(\mathbf{q}) = \sum_{j=1}^{N} \mathbf{A}_{j}(\mathbf{q}) = \sum_{j=1}^{N} A_{j} \exp(i\mathbf{q}\mathbf{r}_{j})$$
(3) Generalized

Direct generalization of Eq. (3) for the scattering of a continuous object with volume V (note: summation \rightarrow integration; $A_i \rightarrow \rho(\mathbf{r}) d\mathbf{r}$ according to Eq. (1)):

$$\mathbf{A}(\mathbf{q}) = \int_{V} \rho(\mathbf{r}) \exp(i\mathbf{q}\mathbf{r}) \,\mathrm{d}\mathbf{r} \tag{4}$$
 Final formula

Final intensity of diffraction is calculated according to: $|(\mathbf{q}) \propto |\mathbf{A}(\mathbf{q})|^2$

Example 1 :: Basic formula: $\mathbf{A}(\mathbf{q}) = \int \rho(\mathbf{r}) \exp[i\mathbf{q}\mathbf{r}] d\mathbf{r} \rightarrow in SAXS$

SAXS = Small-Angle X-ray Scattering (objects: 1000-10A; diffraction angles: <2deg for CuK α)

Dilute solution \Rightarrow spheres scatter independently \Rightarrow particulate scattering.

[1] Scattering of sphere with radius R can be derived from key formula:

$$A\left(\mathbf{q}\right) = \int_{V} \rho\left(\mathbf{r}\right) \exp\left[i\mathbf{q}\mathbf{r}\right] d\mathbf{r}$$

[2] The formula is re-written in polar coordinates:

$$A\left(\mathbf{q}\right) = \int_{r=0}^{+\infty} \int_{\Theta=0}^{\pi} \int_{\Phi=0}^{2\pi} \rho\left(r,\Theta,\Phi\right) \, \exp\left[iqr\cos\Theta\right] \, r^2\sin\Theta \, dr \, d\Theta \, d\Phi$$

[3] The rest is only mathematics; results:

$$A(q) = \rho_0 V \frac{3\left(\sin\left(qR\right) - qR\cos\left(qR\right)\right)}{\left(qR\right)^3}$$

$$I(q) = |A(q)|^{2} = \rho_{0}^{2} V^{2} \frac{9\left(\sin\left(qR\right) - qR\cos\left(qR\right)\right)^{2}}{\left(qR\right)^{6}}$$

Complete derivation.



Conclusion: If the scattering curve has this shape, scattering objects are homogeneous spheres.

Example 2 :: Basic formula: $\mathbf{A}(\mathbf{q}) = \int \rho(\mathbf{r}) \exp[i\mathbf{q}\mathbf{r}] d\mathbf{r} \rightarrow i\mathbf{n}$ WAXS

WAXS = Wide-Angle X-ray Scattering (objects: crystals; diffraction angles 5-90deg for CuK α)

General diffraction theory

! RDG approximation

- \Rightarrow no multiple scattering
- \Rightarrow scatterers = arbitrary objects

 $I(\mathbf{q}) \propto |\mathbf{A}(\mathbf{q})|^2$ ______

$$\mathbf{A}(\mathbf{q}) = \int_{V} \rho(\mathbf{r}) \exp(i\mathbf{q}\mathbf{r}) \,\mathrm{d}\mathbf{r}$$

We sum waves of all volume elements dV of an object, considering phase shifts. $(\rho(\mathbf{r})d\mathbf{r} = \text{contribution of 1 volume element})$



Note – volume element: $dV = dx \cdot dy \cdot dz = dr$

Diffraction by crystals

Kinematic diffraction theory = KDT

- \Rightarrow no multiple scattering
- \Rightarrow scatterers = atoms

$$I(hkl) \propto |F(hkl)|^2$$

$$F(hkl) = \sum_{j=1}^{N} f_j \, \exp[2\pi i(hx_j + ky_j + lz_j)]$$

We sum waves from all atoms in the unit cell, considering their phase shifts \sim positions. (f_i = atom scattering factor = contribution of an atom)



Example 3 :: Calculation of diffraction pattern

Calculation of TEM/SAED powder pattern for Au nanocrystals in Python/Jupyter.

(1) Input for our calculation:

Known crystal structure of Au cubic structure, fcc, a = 4.08 Å

(3) Output of our calculation:

Calculated PXRD diffractogram of polycrystalline Au (and its comparison with experimental TEM/SAED)



(2) Program and formulas for our calculation:

Link to calculation in Jupyter

- Program: Jupyter/Python (without any specific modules)
- Basic formulas: only those shown in the introductory lecture of this course
- Supplementary data: atomic scattering factors + corrections for LP, vibrations, multiplicity

Note1 :: Our ab initio PXRD calculation in Python

We should know that the calculation based on our own code has serious limitations...

- We have learnt how to calculate powder diffraction patterns *ab initio* (success!), and our calculation was quite precise, BUT...
- Limitation #1: We used a lot of simplifications/approximations:
 - kinematic diffraction theory, atom scattering factors from XRD, T(isotropic)...
 - BUT the result was good (small nanocrystals: dynamic effects weak, approximations Ok)
- Limitation #2: The atom positions were hardcoded, symmetry not taken into account...
 - our code is rather inflexible, more demo than real program
 - for more complex structures this would be very impractical
- Limitation #3: We have re-invented the wheel, because there are professional, better, more effective and user-friendly programs for this task, such as:

 - Recently also Python solutions to do this → see next slide
- Limitation #4: We should not forget that this was not the structure analysis:
 - our calculation: known structure \rightarrow diffraction pattern (this is straightforward)
 - real life: experimental diffraction pattern \rightarrow solve the structure (this is more difficult)

CONCLUSIONS:

Comparison of experimental and calculated diffraction patterns = **structure identification**. Determination of unknown structure from its diffraction pattern = **structure analysis**. We did structure identification – for structure analysis see textbooks of crystallography.

Note2 :: Better, universal PXRD calculation in Python

Calculation based on standard Python modules = universal + just 10 lines of code!

😵 Spyder (Python 3.10)



Spyder, script using EDIFF (<u>https://pypi.org/project/ediff</u>), which is build on <u>pymatgen</u>.

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Appendix

Powder TEM/SAED diffractograms – standard processing

This part is optional (not at exams)

Previous appendix = theory + sample calculation in Python/Jupyter

This appendix = real life = how it can be done with standard software



Final 1D diffraction pattern

TEM/SAED :: Standard processing (step 2)

Structure Select Options Diffraction Refinement Windows Special

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In the second step, we calculate the theoretical PXRD diffraction pattern of the (expected) structure SW: PowderCell

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	initial data			d
	lattice consta	C:\MIREK\PRAC_DIFF\PC	ELL\1AU\pcell_au	General algorithm:
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	, cell vol: 67.917 Ĺ	ł density: 19.263 g/cmł rel. mass: 787.8	66 mass abs coef: 115.266 cm	 atom positions
	name 2 1 <mark>Au</mark>	Z ion Wyck x y z 79 Au 4a 0.00000 0.00000 0	: SOF B (temp).00000 1.0000 0.5000	symmetry
	po e	wder diffraction xperiment phase options HKL - list		(2) Define diffrac- tion experiment:
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TEM/SAED :: Standard processing (step 3)



Conclusions:

- 1) We should re-emphasize that this is not a structure analysis.
- In fact we do identification of the structures by fingerprint method – each substance has more-or-less unique unit cell.
- 3) On the other hand, we should not that this type of simple analyses is quite frequent in TEM see lecture about IMA.
- 4) Finally, this could be a basis for more complex TEM/ED work.

In the third step, we compare the experimental and calculated diffraction pattern; the structure is identified if they match.

Notes:

- We can index the diffractions, because
 PowderCell does the indexation automatically
- Even if not, we could do it ourselves, as we can calculate distances (Ex.1) and recalculate diffraction vectors (Ex.2).
- This diffractogram reconfirms that the intensities from XRD and SAED are quite comparable, if the investigated crystals are small.

Appendix Kinematic vs. dynamic diffraction theory

This part is optional (not at exams)

Supplement :: Kinematic vs. dynamic theory of diffraction

- The formulas derived here were based on Raylegh-Debye-Gans approximation (RDG) (RDG comes from general theory of diffraction (Assumption: negligible multiple scattering in the diffracting object
- In crystallography, the equivalent to RDG is thin crystal approximation = TCA (Assumption: negligible multiple scattering in the crystal



If TCA holds, we can use KDT. If multiple scattering occurs, we must use Dynamic Diffraction Theory (DDT)

- XRD: multiple scattering mostly negligible, KDT is a good approximation. ED: multiple scattering usually not negligible \Rightarrow DDT gives more precise results.
- BUT here we use KDT for electrons why?
 - \Rightarrow kinematic theory it is easier for understanding/calculations than dynamic theory
 - \Rightarrow for nanocrystals (used as fillers for polymers) KDT holds quite well proof: Ex. 6/6 100